

Electronic Supplementary Information

ZnO/Porous GaN Heterojunction and its Application as Humidity Sensor

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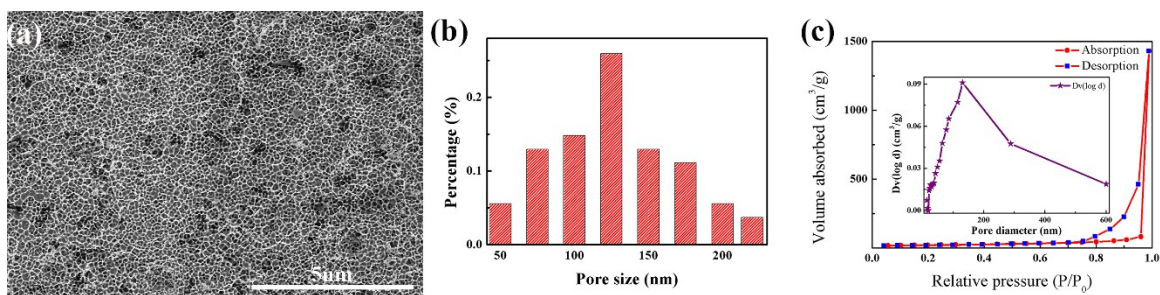


Fig. S1 (a) SEM images of PGAN. (b) Pore size distribution histograms of PGAN. (c) N₂ adsorption-desorption isotherm curve and pore size distribution (inset) of PGAN.